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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
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EXAMINER

MAI, SON LUU

ART UNIT

PAPER NUMBER

2818

DATE MAILED: 10/18/2002

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	Application No. 09/808,750	Applicant(s) VO, HUY THANH
	Examiner Son L. Mai	Art Unit 2818

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --
Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

1) Responsive to communication(s) filed on ____.

2a) This action is **FINAL**. 2b) This action is non-final.

3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

4) Claim(s) 1-54 is/are pending in the application.

4a) Of the above claim(s) _____ is/are withdrawn from consideration.

5) Claim(s) _____ is/are allowed.

6) Claim(s) 1-54 is/are rejected.

7) Claim(s) _____ is/are objected to.

8) Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

9) The specification is objected to by the Examiner.

10) The drawing(s) filed on _____ is/are: a) accepted or b) objected to by the Examiner.

Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).

11) The proposed drawing correction filed on 27 August 2002 is: a) approved b) disapproved by the Examiner.

If approved, corrected drawings are required in reply to this Office action.

12) The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. §§ 119 and 120

13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).

a) All b) Some * c) None of:

1. Certified copies of the priority documents have been received.
2. Certified copies of the priority documents have been received in Application No. _____.
3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).

a) The translation of the foreign language provisional application has been received.

15) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

Attachment(s)

1) Notice of References Cited (PTO-892)
2) Notice of Draftsperson's Patent Drawing Review (PTO-948)
3) Information Disclosure Statement(s) (PTO-1449) Paper No(s) ____ .
4) Interview Summary (PTO-413) Paper No(s). ____ .
5) Notice of Informal Patent Application (PTO-152)
6) Other: ____ .

DETAILED ACTION

1. This office action is responsive to the amendment filed on 08-27-02. Claims 1-54 remain pending in the application.

Drawings

2. The proposed drawing correction and/or the proposed substitute sheets of drawings, filed on 08-27-02 have been approved. A proper drawing correction or corrected drawings are required in reply to the Office action to avoid abandonment of the application. The correction to the drawings will not be held in abeyance.

Claim Rejections - 35 USC § 102

3. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless –

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

4. Claims 1-54 are rejected under 35 U.S.C. 102(b) as being clearly anticipated by Tanoi (U.S. Patent 5,708,621).

Regarding claims 1, 8, 15, 26, 30, 42 and 45, Tanoi discloses a memory array (1 in fig. 1) comprising: a number of memory cells (6) having a first source/drain region and a second source/drain region and a gate region (parts of an access transistor in a dynamic random access memory); a number of source lines (not shown) coupled to the first source/drain region of at least one memory cell; a number of bit lines (4) coupled to the second source/drain region of at least one memory cell; a number of wordlines (2) coupled to the gate region of at least one memory cell; a strapping line (118 in fig. 16) of

lower resistance than the wordlines coupled to a single wordline wherein the strapping line bypasses a portion of the single wordline, and wherein the strapping line is spaced apart from adjacent conductive structures by a distance greater than a wordline pitch (fig. 18); and at least two channels (122, 126 in fig. 18) connecting the strapping line to a first and second end of the portion of the single wordline.

Regarding claims 2, 3, 6, 7, 9, 10, 16, 17, 20, 21, 27, 28, 31, 32, 39, 44, 46, 47, 50, 51, Tanoi teaches at column 7, lines 54-57, the strapping lines comprise metal.

Regarding claims 4, 29, Tanoi shows in figure 16, the portion of the wordline bypassed by the strapping line comprises a first half of the memory cells coupled to the wordline.

Regarding claims 5, 19, 37 and 49, Tanoi teaches a memory array, comprising: a number of memory cells having a first source/drain region and a second source/drain region and a gate region (parts of an access transistor in a dynamic random access memory); a number of source lines (not shown) coupled to the first source/drain region of at least one memory cell; a number of bit lines (4 in fig. 1) coupled to the second source/drain region of at least one memory cell; a number of wordlines (2 in fig. 1) coupled to the gate region of at least one memory cell; a plurality of strapping lines (50 in fig. 4) of lower resistance than the wordlines coupled to at least one of the number of wordlines wherein the strapping lines (lines 50 consisting of two strapping lines joining at interconnecting plug 60) bypass a plurality of portions (54, 56) of a single wordline; and a plurality of channels (60 in fig. 6) connecting the plurality of strapping layers to the wordline.

Regarding claims 11, 22, 33, Tanoi shows in figure 4, the portions (38, 40, 42) of the wordlines (37) in the array bypassed by the number of strapping devices (line 36 has 2 portions) comprises a plurality of end portions (44, 46,48) of the wordlines.

Regarding claims 12, 23, 34, 52, Tanoi shows in figure 4, the strapping devices are located on alternating wordlines in the array.

Regarding claims 13, 24, 35, 53, Tanoi shows in figure 16, the strapping devices (108, 118) are located on adjacent wordlines and staggered along the wordlines such that the portions of the adjacent wordlines that are bypassed are not adjacent to each other.

Regarding claims 14, 18, 25, 36, 54, Tanoi shows in figure 16, the strapping devices (108, 118) strap a first half portion of a number of even wordlines in the array and a second half portion of a number of odd wordlines.

Regarding claims 38, 43, the method of reducing a wordline RC time constant reads on figure 16 of Tanoi, wherein activating a second number of transistors coupled to a second portion (114) of a wordline comprises: sending a signal through a first channel(112) to a metal strapping line(108); sending the signal through the metal strapping line; and sending the signal through a second channel (116) to the second portion(114) of the wordline.

Regarding claim 40, the method of reducing a wordline RC time constant as claimed reads on figure 16 wherein activating a first number of transistors coupled to a first portion (110) of a wordline comprising activating a first number of transistors coupled to a first half of the wordline.

Regarding claims 41, 48, the method of reducing a wordline RC time constant reads on figure 4, wherein activating a selected row in a memory array comprises bypassing multiple portions (38, 40) of the wordline (37) using multiple strapping devices (strapping line 36 has 2 portions connecting at interconnecting plug 46) of lower resistance than the wordline.

Response to Arguments

5. Applicant's arguments filed 08-27-02 have been fully considered but they are not persuasive.

In the Remarks on pages 8 and 9, the Applicant argued that the Tanoi patent does not teach two features: (1) at least two channels connecting each strapping line to a first and second end of the portion of a single wordline, and (2) the strapping lines bypass a plurality of portions of a single wordline.

On the contrary, as pointed out in the above rejections, Tanoi shows at least in one embodiment in figures 16-18, two channels (interconnecting plugs 122,126) connecting a strapping line 118 to two ends of a portion of a single wordline. To the second point, Tanoi shows in figure 4, the strapping line 50, consisting of two portions connecting at interconnecting plug 60, bypasses portions 54 and 56 of a single wordline. Therefore, all the claims are anticipated by Tanoi.

Conclusion

6. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP

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§ 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Son L. Mai whose telephone number is 305-3497. The examiner can normally be reached on 8am to 6pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on 308-4910. The fax phone numbers for the organization where this application or proceeding is assigned are 308-7724 for regular communications and 308-7724 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 308-0956.



Son L. Mai
Primary Examiner
Art Unit 2818

10-16-2002